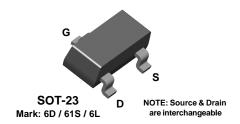


2N5457 2N5458 2N5459

**MMBF5457 MMBF5458 MMBF5459** 





# **N-Channel General Purpose Amplifier**

This device is a low level audio amplifier and switching transistors, and can be used for analog switching applications. Sourced from Process 55.

#### **Absolute Maximum Ratings\*** TA = 25°C unless otherwise noted

| Symbol                            | Parameter  | Value       | Units |
|-----------------------------------|--|-------------|-------|
| $V_{DG}$                          | Drain-Gate Voltage                               | 25          | V     |
| V <sub>GS</sub>                   | Gate-Source Voltage                              | - 25        | V     |
| I <sub>GF</sub>                   | Forward Gate Current                             | 10          | mA    |
| T <sub>J</sub> , T <sub>stg</sub> | Operating and Storage Junction Temperature Range | -55 to +150 | °C    |

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

# Thermal Characteristics TA = 25°C unless otherwise noted

| Symbol          | Characteristic                          | N           | <b>l</b> ax    | Units |
|-----------------|---|-------------|----------------|-------|
|                 |   | 2N5457-5459 | *MMBF5457-5459 |       |
| $P_D$           | Total Device Dissipation                | 625         | 350            | mW    |
|                 | Derate above 25°C                       | 5.0         | 2.8            | mW/°C |
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case    | 125         |                | °C/W  |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 357         | 556            | °C/W  |

<sup>\*</sup>Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

# **N-Channel General Purpose Amplifier**

(continued)

|  | ectrical Characteri |
|--|---------------------|

TA = 25°C unless otherwise noted

| Symbol | Parameter | Test Conditions | Min | Тур | Max | Units |
|--------|-----------|-----------------|-----|-----|-----|-------|
|        |           |                 |     |     |     |       |

### **OFF CHARACTERISTICS**

| V <sub>(BR)GSS</sub> | Gate-Source Breakdown Voltage | $I_G = 10 \mu A, V_{DS} = 0$  |                              | - 25           |                         |                | V           |
|----------------------|-------------------------------|---|------------------------------|----------------|-------------------------|----------------|-------------|
| I <sub>GSS</sub>     | Gate Reverse Current          | $V_{GS} = -15 \text{ V}, V_{DS} = 0$<br>$V_{GS} = -15 \text{ V}, V_{DS} = 0, T_{A} = 0$   | 100°C                        |                |                         | - 1.0<br>- 200 | nA<br>nA    |
| V <sub>GS(off)</sub> | Gate-Source Cutoff Voltage    | $V_{DS} = 15 \text{ V}, V_{DS} = 0, T_{A} = 0$ $V_{DS} = 15 \text{ V}, I_{D} = 10 \text{ nA}$   | 5457<br>5458                 | - 0.5<br>- 1.0 |                         | - 6.0<br>- 7.0 | V           |
| V <sub>GS</sub>      | Gate-Source Voltage           | V <sub>DS</sub> = 15 V, I <sub>D</sub> = 100 μA<br>V <sub>DS</sub> = 15 V, I <sub>D</sub> = 200 μA<br>V <sub>DS</sub> = 15 V, I <sub>D</sub> = 400 μA | 5459<br>5457<br>5458<br>5459 | - 2.0          | - 2.5<br>- 3.5<br>- 4.5 | - 8.0          | V<br>V<br>V |

### **ON CHARACTERISTICS**

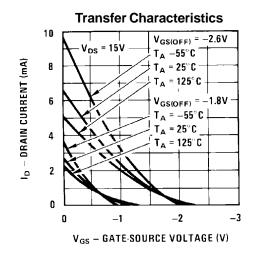
| I <sub>DSS</sub> | Zero-Gate Voltage Drain Current* | $V_{DS} = 15 \text{ V}, V_{GS} = 0$ | 5457 | 1.0 | 3.0 | 5.0 | mΑ |
|------------------|----------------------------------|-------------------------------------|------|-----|-----|-----|----|
|                  |                                  |                                     | 5458 | 2.0 | 6.0 | 9.0 | mΑ |
|                  |                                  |                                     | 5459 | 4.0 | 9.0 | 16  | mΑ |

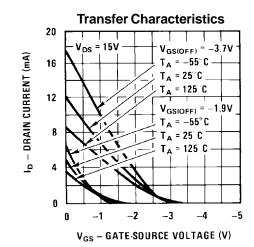
### SMALL SIGNAL CHARACTERISTICS

| 9 <sub>fs</sub> | Forward Transfer Conductance* | $V_{DS} = 15 \text{ V}, V_{GS} = 0, f = 1.0 \text{ kHz}$  |                      |     |                      |                         |
|-----------------|-------------------------------|---|----------------------|-----|----------------------|-------------------------|
|                 |                               | 5457<br>5458<br>5459  | 1000<br>1500<br>2000 |     | 5000<br>5500<br>6000 | μmhos<br>μmhos<br>μmhos |
| gos             | Output Conductance*           | $V_{DS} = 15 \text{ V}, V_{GS} = 0, f = 1.0 \text{ kHz}$  |                      | 10  | 50                   | μmhos                   |
| Ciss            | Input Capacitance             | V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0, f = 1.0 MHz  |                      | 4.5 | 7.0                  | pF                      |
| Crss            | Reverse Transfer Capacitance  | $V_{DS} = 15 \text{ V}, V_{GS} = 0, f = 1.0 \text{ MHz}$  |                      | 1.5 | 3.0                  | pF                      |
| NF              | Noise Figure                  | $V_{DS} = 15 \text{ V}, V_{GS} = 0, f = 1.0 \text{ kHz}, R_G = 1.0 \text{ megohm}, BW = 1.0 \text{ Hz}$ |                      |     | 3.0                  | dB                      |

<sup>\*</sup>Pulse Test: Pulse Width ≤ 300 ms, Duty Cycle ≤ 2%

# **Typical Characteristics**

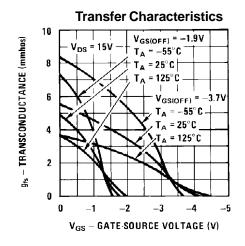


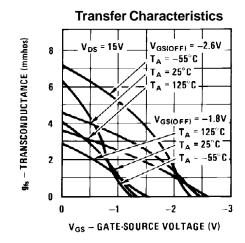


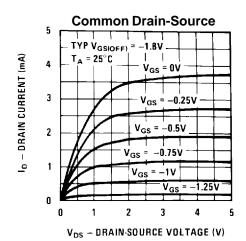
# **N-Channel General Purpose Amplifier**

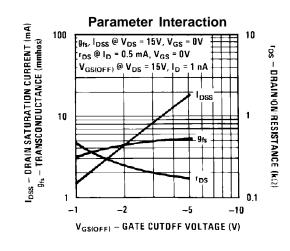
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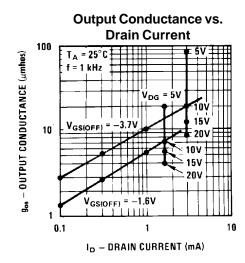
# Typical Characteristics (continued)

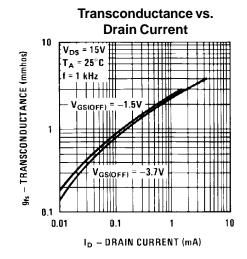








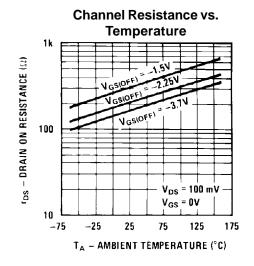


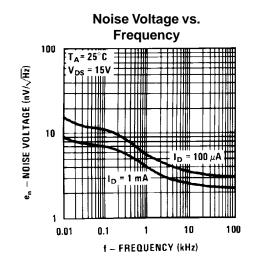


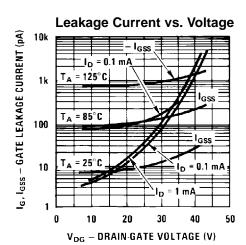
# **N-Channel General Purpose Amplifier**

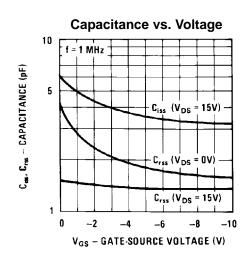
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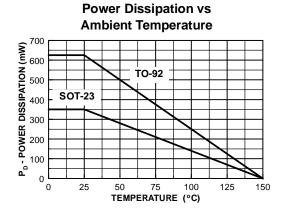
# Typical Characteristics (continued)











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### 2N5457

N-Channel General Purpose Amplifier

#### **Contents**

- General description
- Product status/pricing/packaging
- Order Samples
- Qualification Support

### **General description**

This device is a low level audio amplifier and switching transistors, and can be used for analog switching applications. Sourced from Process 55.

back to top

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Product status/pricing/packaging

BUY

| Product     | Product status  | Pb-free Status     | Pricing* | Package type | Leads | Packing method Package Marking Conventi |  |  |
|-------------|-----------------|--------------------|----------|--------------|-------|---|--|--|
| 2N5457      | Full Production | Full<br>Production | \$0.082  | <u>TO-92</u> | 3     | BULK                                    | Line 1: <b>\$Y</b> (Fairchild logo)<br>& <b>Z</b> (Asm. Plant Code)<br>& <b>3</b> (3-Digit Date Code)<br>Line 2: 2N Line 3: 5457 |  |
| 2N5457_D26Z | Full Production | Full<br>Production | N/A      | <u>TO-92</u> | 3     | TAPE REEL                               | Line 1: <b>\$Y</b> (Fairchild logo)<br>& <b>Z</b> (Asm. Plant Code)<br>& <b>3</b> (3-Digit Date Code)<br>Line 2: 2N Line 3: 5457 |  |
| 2N5457_D27Z | Full Production | Full<br>Production | N/A      | <u>TO-92</u> | 3     | TAPE REEL                               | Line 1: <b>\$Y</b> (Fairchild logo)<br>& <b>Z</b> (Asm. Plant Code)<br>& <b>3</b> (3-Digit Date Code)<br>Line 2: 2N Line 3: 5457 |  |
| 2N5457_D74Z | Full Production |                    | N/A      | <u>TO-92</u> | 3     |   | Line 1: <b>\$Y</b> (Fairchild logo) & <b>Z</b> (Asm. Plant Code)   |  |

|             |                 | Full<br>Production |     |              |   |      | & <b>3</b> (3-Digit Date Code)<br>Line 2: 2N Line 3: 5457  |
|-------------|-----------------|--------------------|-----|--------------|---|------|--|
| 2N5457_D75Z | Full Production | Full<br>Production | N/A | <u>TO-92</u> | 3 | АММО | Line 1: <b>\$Y</b> (Fairchild logo)<br>& <b>Z</b> (Asm. Plant Code)<br>& <b>3</b> (3-Digit Date Code)<br>Line 2: 2N Line 3: 5457 |
| 2N5457_L99Z | Lifetime Buy    | <b>Ø</b>           | N/A | <u>TO-92</u> | 3 | BULK | Line 1: NO MARK  |

<sup>\*</sup> Fairchild 1,000 piece Budgetary Pricing

\*\* A sample button will appear if the part is available through Fairchild's on-line samples program. If there is no sample button, please contact a Fairchild distributor to obtain samples



Indicates product with Pb-free second-level interconnect. For more information click here.

Package marking information for product 2N5457 is available. Click here for more information .

### back to top

### **Qualification Support**

Click on a product for detailed qualification data

| Product     |  |  |  |  |  |
|-------------|--|--|--|--|--|
| 2N5457      |  |  |  |  |  |
| 2N5457_D26Z |  |  |  |  |  |
| 2N5457_D27Z |  |  |  |  |  |
| 2N5457_D74Z |  |  |  |  |  |
| 2N5457_D75Z |  |  |  |  |  |
| 2N5457_L99Z |  |  |  |  |  |

#### back to top

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